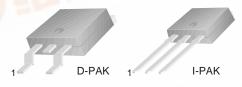


### MJD31/31C

# General Purpose Amplifier Low Speed Switching Applications

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular TIP31 and TIP31C



### 1.Base 2.Collector 3.Emitter

### **NPN Epitaxial Silicon Transistor**

### Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
020	: MJD31	40	V
	: MJD31C	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: MJDH31	40	V
	: MJD31C	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	3	Α
I <sub>CP</sub>	Collector Current (Pulse)	1	Α
I <sub>B</sub>	Base Current	W W	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	15	W
	Collector Dissipation (T <sub>a</sub> =25°C)	1.56	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage : MJD31	I <sub>C</sub> = 30mA, I <sub>B</sub> = 0	40	-51	V
	: MJD31C	C 33 7 B 3	100	W.	V
I <sub>CEO</sub>	Collector Cut-off Current	. a.l. 1 de	7.49	100	
	: MJD31	$V_{CE} = 40V, I_{B} = 0$	AND AND A	50	μΑ
	: MJD31C	$V_{CE} = 60V, I_{B} = 0$		50	μΑ
I <sub>CES</sub>	Collector Cut-off Current	A ((C)			
	: MJD31	$V_{CE} = 40V, V_{BE} = 0$		20	μΑ
	: MJD31C	$V_{CE} = 100V, V_{BE} = 0$		20	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$		1	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = 4V, I_{C} = 1A$	25		
		$V_{CE} = 4V, I_{C} = 3A$	10	50	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	$I_C = 3A, I_B = 375mA$		1.2	V
V <sub>BE</sub> (on)	* Base-Emitter ON Voltage	$V_{CE} = 4A$ , $I_C = 3A$		1.8	V
f⊤	Current Gain Bandwidth Product	$V_{CF} = 10V, I_{C} = 500mA$	3		MHz

\* Pulse Test: PW≤300μs, Duty Cycle≤2%

# **Typical Characteristics**

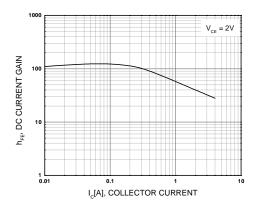


Figure 1. DC current Gain

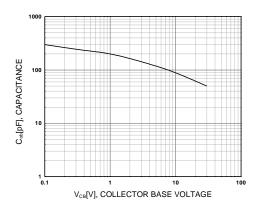


Figure 3. Collector Capacitance

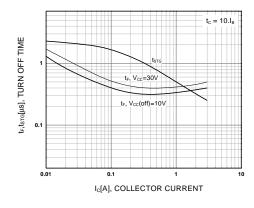


Figure 5. Turn Off Time

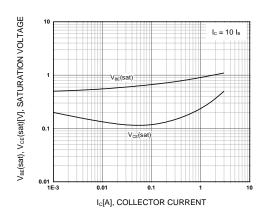


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

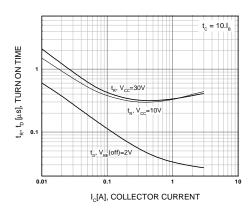


Figure 4. Turn On Time

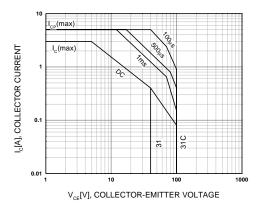


Figure 6. Safe Operating

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# Typical Characteristics (Continued)

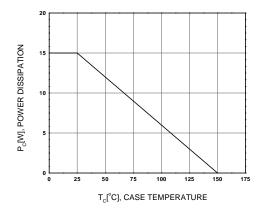
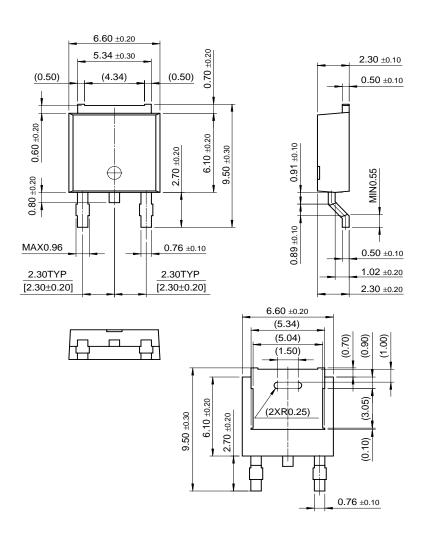


Figure 7. Power Derating

# **Package Demensions**

# D-PAK



Dimensions in Millimeters

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